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Applications of "Embedded - Microcontrollers"

Details	
Product Status	Not For New Designs
Core Processor	M32C/80
Core Size	16/32-Bit
Speed	32MHz
Connectivity	CANbus, I²C, IEBus, SIO, UART/USART
Peripherals	DMA, WDT
Number of I/O	85
Program Memory Size	384KB (384K x 8)
Program Memory Type	FLASH
EEPROM Size	4K x 8
RAM Size	24K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	A/D 26x10b; D/A 2x8b
Oscillator Type	Internal
Operating Temperature	-20°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	100-BQFP
Supplier Device Package	100-QFP (14x20)
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/m30853fhfp-u5

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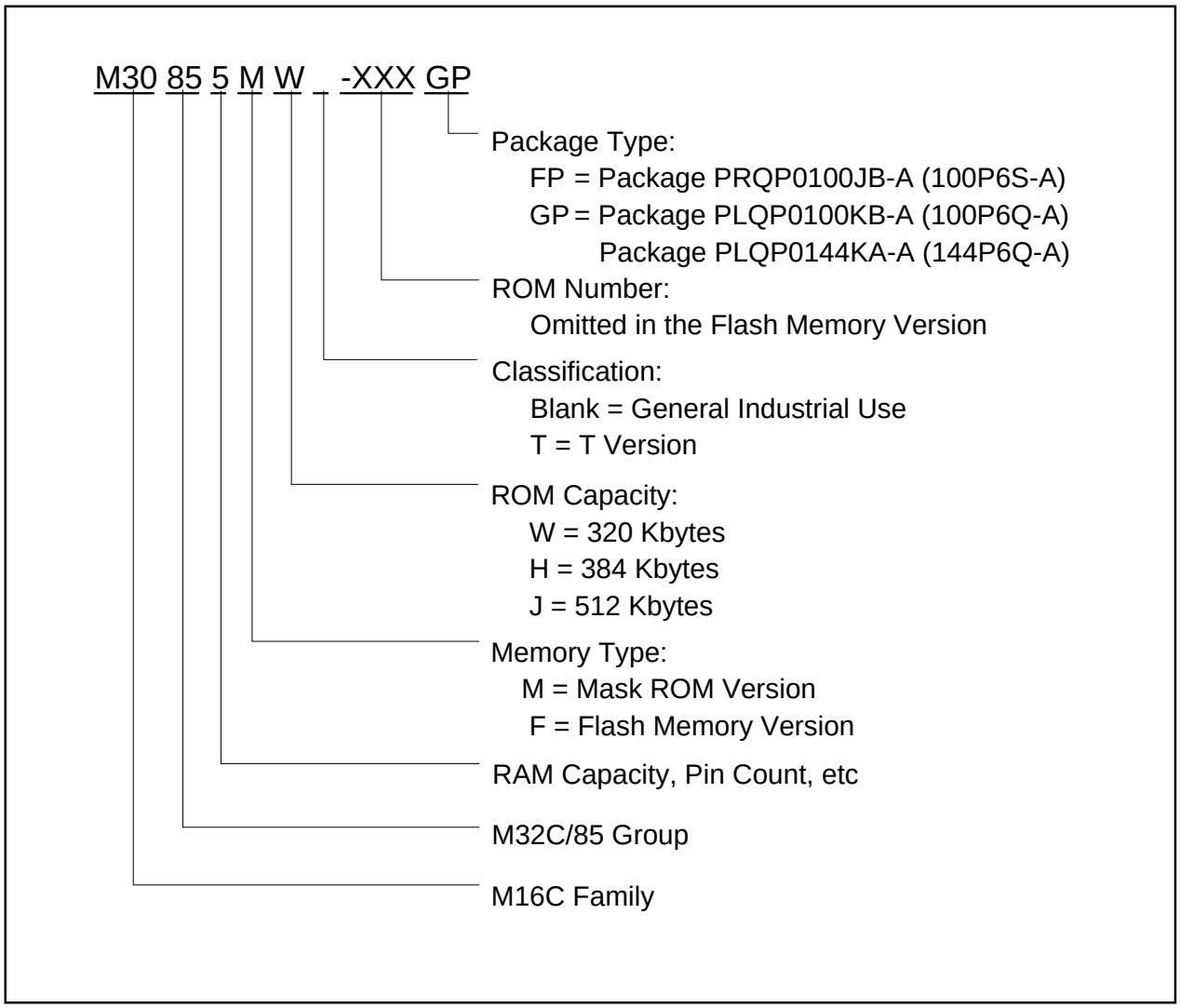


Figure 1.2 Product Numbering System

Table 1.4 Pin Characteristics for 144-Pin Package (Continued)

Pin No.	Control Pin	Port	Interrupt Pin	Timer Pin	UART/CAN Pin	Intelligent I/O Pin	Analog Pin	Bus Control Pin(1)
49		P13$_6$						
50		P13$_5$						
51		P13$_4$						
52		P5$_7$						$\overline{\text{RDY}}$
53		P5$_6$						ALE
54		P5$_5$						$\overline{\text{HOLD}}$
55		P5$_4$						$\overline{\text{HLDA}}$/ALE
56		P13$_3$						
57	V_{SS}							
58		P13$_2$						
59	V_{CC2}							
60		P13$_1$						
61		P13$_0$						
62		P5$_3$						CLK$_{OUT}$/BCLK/ALE
63		P5$_2$						$\overline{\text{RD}}$
64		P5$_1$						$\overline{\text{WRH}}$/$\overline{\text{BHE}}$
65		P5$_0$						$\overline{\text{WRL}}$/$\overline{\text{WR}}$
66		P12$_7$						
67		P12$_6$						
68		P12$_5$						
69		P4$_7$						$\overline{\text{CS0}}$/A$_{23}$
70		P4$_6$						$\overline{\text{CS1}}$/A$_{22}$
71		P4$_5$						$\overline{\text{CS2}}$/A$_{21}$
72		P4$_4$						$\overline{\text{CS3}}$/A$_{20}$
73		P4$_3$						A$_{19}$
74	V_{CC2}							
75		P4$_2$						A$_{18}$
76	V_{SS}							
77		P4$_1$						A$_{17}$
78		P4$_0$						A$_{16}$
79		P3$_7$						A$_{15}$(/D$_{15}$)
80		P3$_6$						A$_{14}$(/D$_{14}$)
81		P3$_5$						A$_{13}$(/D$_{13}$)
82		P3$_4$						A$_{12}$(/D$_{12}$)
83		P3$_3$						A$_{11}$(/D$_{11}$)
84		P3$_2$						A$_{10}$(/D$_{10}$)
85		P3$_1$						A$_9$(/D$_9$)
86		P12$_4$						
87		P12$_3$						
88		P12$_2$						
89		P12$_1$						
90		P12$_0$						
91	V_{CC2}							
92		P3$_0$						A$_8$(/D$_8$)
93	V_{SS}							
94		P2$_7$					AN2$_7$	A$_7$(/D$_7$)
95		P2$_6$					AN2$_6$	A$_6$(/D$_6$)
96		P2$_5$					AN2$_5$	A$_5$(/D$_5$)

NOTES:

1. Bus control pins in M32C/85T cannot be used.

Table 1.4 Pin Characteristics for 144-Pin Package (Continued)

Pin No.	Control Pin	Port	Interrupt Pin	Timer Pin	UART/CAN Pin	Intelligent I/O Pin	Analog Pin	Bus Control Pin(1)
97		$P2_4$					$AN2_4$	A_4(/D_4)
98		$P2_3$					$AN2_3$	A_3(/D_3)
99		$P2_2$					$AN2_2$	A_2(/D_2)
100		$P2_1$					$AN2_1$	A_1(/D_1)
101		$P2_0$					$AN2_0$	A_0(/D_0)
102		$P1_7$	$\overline{INT5}$					D_{15}
103		$P1_6$	$\overline{INT4}$					D_{14}
104		$P1_5$	$\overline{INT3}$					D_{13}
105		$P1_4$						D_{12}
106		$P1_3$						D_{11}
107		$P1_2$						D_{10}
108		$P1_1$						D_9
109		$P1_0$						D_8
110		$P0_7$					$AN0_7$	D_7
111		$P0_6$					$AN0_6$	D_6
112		$P0_5$					$AN0_5$	D_5
113		$P0_4$					$AN0_4$	D_4
114		$P11_4$						
115		$P11_3$				$INPC1_3$/$OUTC1_3$		
116		$P11_2$				$INPC1_2$/$OUTC1_2$/ISRxD1/$BE1_{IN}$		
117		$P11_1$				$INPC1_1$/$OUTC1_1$/ISCLK1		
118		$P11_0$				$INPC1_0$/$OUTC1_0$/ISTxD1/$BE1_{OUT}$		
119		$P0_3$					$AN0_3$	D_3
120		$P0_2$					$AN0_2$	D_2
121		$P0_1$					$AN0_1$	D_1
122		$P0_0$					$AN0_0$	D_0
123		$P15_7$					$AN15_7$	
124		$P15_6$					$AN15_6$	
125		$P15_5$					$AN15_5$	
126		$P15_4$					$AN15_4$	
127		$P15_3$					$AN15_3$	
128		$P15_2$				ISRxD0	$AN15_2$	
129		$P15_1$				ISCLK0	$AN15_1$	
130	V_{SS}							
131		$P15_0$				ISTxD0	$AN15_0$	
132	V_{CC1}							
133		$P10_7$	$\overline{KI_3}$				AN_7	
134		$P10_6$	$\overline{KI_2}$				AN_6	
135		$P10_5$	$\overline{KI_1}$				AN_5	
136		$P10_4$	$\overline{KI_0}$				AN_4	
137		$P10_3$					AN_3	
138		$P10_2$					AN_2	
139		$P10_1$					AN_1	
140	AV_{SS}							
141		$P10_0$					AN_0	
142	V_{REF}							
143	AV_{CC}							
144		$P9_7$			RxD4/SCL4/STxD4		$\overline{ADTRG}$	

NOTES:

1. Bus control pins in M32C/85T cannot be used,

Table 1.5 Pin Characteristics for 100-Pin Package (Continued)

Package Pin No.		Control Pin	Port	Interrupt Pin	Timer Pin	UART/CAN Pin	Intelligent I/O Pin	Analog Pin	Bus Control Pin(1)
FP	GP								
51	49		$P4_3$						A_{19}
52	50		$P4_2$						A_{18}
53	51		$P4_1$						A_{17}
54	52		$P4_0$						A_{16}
55	53		$P3_7$						A_{15}(/D_{15})
56	54		$P3_6$						A_{14}(/D_{14})
57	55		$P3_5$						A_{13}(/D_{13})
58	56		$P3_4$						A_{12}(/D_{12})
59	57		$P3_3$						A_{11}(/D_{11})
60	58		$P3_2$						A_{10}(/D_{10})
61	59		$P3_1$						A_9(/D_9)
62	60	V_{CC2}							
63	61		$P3_0$						A_8(/D_8)
64	62	V_{SS}							
65	63		$P2_7$					$AN2_7$	A_7(/D_7)
66	64		$P2_6$					$AN2_6$	A_6(/D_6)
67	65		$P2_5$					$AN2_5$	A_5(/D_5)
68	66		$P2_4$					$AN2_4$	A_4(/D_4)
69	67		$P2_3$					$AN2_3$	A_3(/D_3)
70	68		$P2_2$					$AN2_2$	A_2(/D_2)
71	69		$P2_1$					$AN2_1$	A_1(/D_1)
72	70		$P2_0$					$AN2_0$	A_0(/D_0)
73	71		$P1_7$	$\overline{INT5}$					D_{15}
74	72		$P1_6$	$\overline{INT4}$					D_{14}
75	73		$P1_5$	$\overline{INT3}$					D_{13}
76	74		$P1_4$						D_{12}
77	75		$P1_3$						D_{11}
78	76		$P1_2$						D_{10}
79	77		$P1_1$						D_9
80	78		$P1_0$						D_8
81	79		$P0_7$					$AN0_7$	D_7
82	80		$P0_6$					$AN0_6$	D_6
83	81		$P0_5$					$AN0_5$	D_5
84	82		$P0_4$					$AN0_4$	D_4
85	83		$P0_3$					$AN0_3$	D_3
86	84		$P0_2$					$AN0_2$	D_2
87	85		$P0_1$					$AN0_1$	D_1
88	86		$P0_0$					$AN0_0$	D_0
89	87		$P10_7$	$\overline{KI_3}$				AN_7	
90	88		$P10_6$	$\overline{KI_2}$				AN_6	
91	89		$P10_5$	$\overline{KI_1}$				AN_5	
92	90		$P10_4$	$\overline{KI_0}$				AN_4	
93	91		$P10_3$					AN_3	
94	92		$P10_2$					AN_2	
95	93		$P10_1$					AN_1	
96	94	AV_{SS}							
97	95		$P10_0$					AN_0	
98	96	V_{REF}							
99	97	AV_{CC}							
100	98		$P9_7$			RxD4/SCL4/STxD4		$\overline{ADTRG}$	

NOTES:

1. Bus control pins in M32C/85T cannot be used.

Table 1.6 Pin Description (100-Pin and 144-Pin Packages) (Continued)

Classsfication	Symbol	I/O Type	Supply Voltage	Function
Main Clock Input	XIN	I	VCC1	I/O pins for the main clock oscillation circuit. Connect a ceramic resonator or crystal oscillator between XIN and XOUT. To apply external clock, apply it to XIN and leave XOUT open
Main Clock Output	XOUT	O	VCC1	
Sub Clock Input	XCIN	I	VCC1	I/O pins for the sub clock oscillation circuit. Connect a crystal oscillator between XCIN and XCOUT. To apply external clock, apply it to XCIN and leave XCOUT open
Sub Clock Output	XCOUT	O	VCC1	
BCLK Output(1)	BCLK	O	VCC2	Outputs BCLK signal
Clock Output	CLKOUT	O	VCC2	Outputs the clock having the same frequency as fC, f8 or f32
$\overline{\text{INT}}$ Interrupt Input	$\overline{\text{INT0}}$ to $\overline{\text{INT2}}$	I	VCC1	Input pins for the $\overline{\text{INT}}$ interrupt
	$\overline{\text{INT3}}$ to $\overline{\text{INT5}}$		VCC2	
$\overline{\text{NMI}}$ Interrupt Input	$\overline{\text{NMI}}$	I	VCC1	Input pin for the $\overline{\text{NMI}}$ interrupt
Key Input Interrupt	$\overline{\text{KI0}}$ to $\overline{\text{KI3}}$	I	VCC1	Input pins for the key input interrupt
Timer A	TA0OUT to TA4OUT	I/O	VCC1	I/O pins for the timer A0 to A4 (TA0OUT is a pin for the N-channel open drain output.)
	TA0IN to TA4IN	I	VCC1	Input pins for the timer A0 to A4
Timer B	TB0IN to TB5IN	I	VCC1	Input pins for the timer B0 to B5
Three-phase Motor Control Timer Output	U, $\overline{\text{U}}$, V, $\overline{\text{V}}$, W, $\overline{\text{W}}$	O	VCC1	Output pins for the three-phase motor control timer
Serial I/O	$\overline{\text{CTS0}}$ to $\overline{\text{CTS4}}$	I	VCC1	Input pins for data transmission control
	$\overline{\text{RTS0}}$ to $\overline{\text{RTS4}}$	O	VCC1	Output pins for data reception control
	CLK0 to CLK4	I/O	VCC1	Inputs and outputs the transfer clock
	RxD0 to RxD4	I	VCC1	Inputs serial data
	TxD0 to TxD4	O	VCC1	Outputs serial data (TxD2 is a pin for the N-channel open drain output.)
I^2C Mode	SDA0 to SDA4	I/O	VCC1	Inputs and outputs serial data (SDA2 is a pin for the N-channel open drain output.)
	SCL0 to SCL4			Inputs and outputs the transfer clock (SCL2 is a pin for the N-channel open drain output.)
Serial I/O Special Function	STxD0 to STxD4	O	VCC1	Outputs serial data when slave mode is selected (STxD2 is a pin for the N-channel open drain output.)
	SRxD0 to SRxD4	I		Inputs serial data when slave mode is selected
	$\overline{\text{SS0}}$ to $\overline{\text{SS4}}$	I	VCC1	Input pins to control serial I/O special function

I : Input O : Output I/O : Input and output

NOTES:

1. Bus control pins in M32C/85T cannot be used.

4. Special Function Registers (SFR)

Address	Register	Symbol	Value after RESET
000016			
000116			
000216			
000316			
000416	Processor Mode Register(1)	PM0	1000 00002(CNVss pin ="L") 0000 00112(CNVss pin ="H")
000516	Processor Mode Register 1	PM1	0016
000616	System Clock Control Register 0	CM0	0000 10002
000716	System Clock Control Register 1	CM1	0010 00002
000816			
000916	Address Match Interrupt Enable Register	AIER	0016
000A16	Protect Register	PRCR	XXXX 00002
000B16	External Data Bus Width Control Register(2)	DS	XXXX 10002(BYTE pin ="L") XXXX 00002(BYTE pin ="H")
000C16	Main Clock Division Register	MCD	XXX0 10002
000D16	Oscillation Stop Detection Register	CM2	0016
000E16	Watchdog Timer Start Register	WDTS	XX16
000F16	Watchdog Timer Control Register	WDC	000X XXXX2
001016 001116 001216	Address Match Interrupt Register 0	RMAD0	00000016
001316	Processor Mode Register 2	PM2	0016
001416 001516 001616	Address Match Interrupt Register 1	RMAD1	00000016
001716	Voltage Detection Register 2(2)	VCR2	0016
001816 001916 001A16	Address Match Interrupt Register 2	RMAD2	00000016
001B16	Voltage Detection Register 1(2)	VCR1	0000 10002
001C16 001D16 001E16	Address Match Interrupt Register 3	RMAD3	00000016
001F16			
002016			
002116			
002216			
002316			
002416			
002516			
002616	PLL Control Register 0	PLC0	0001 X0102
002716	PLL Control Register 1	PLC1	000X 00002
002816 002916 002A16	Address Match Interrupt Register 4	RMAD4	00000016
002B16			
002C16 002D16 002E16	Address Match Interrupt Register 5	RMAD5	00000016
002F16	Low Voltage Detection Interrupt Register(2)	D4INT	0016

X: Indeterminate

Blank spaces are reserved. No access is allowed.

NOTES:

1. The PM01 and PM00 bits in the PM0 register maintain values set before reset, even after software reset or watch-dog timer reset has been performed.
2. These registers in M32C/85T cannot be used.

Address	Register	Symbol	Value after RESET
0030₁₆			
0031₁₆			
0032₁₆			
0033₁₆			
0034₁₆			
0035₁₆			
0036₁₆			
0037₁₆			
0038₁₆ 0039₁₆ 003A₁₆	Address Match Interrupt Register 6	RMAD6	000000₁₆
003B₁₆			
003C₁₆ 003D₁₆ 003E₁₆	Address Match Interrupt Register 7	RMAD7	000000₁₆
003F₁₆			
0040₁₆			
0041₁₆			
0042₁₆			
0043₁₆			
0044₁₆			
0045₁₆			
0046₁₆			
0047₁₆			
0048₁₆	External Space Wait Control Register 0(1)	EWCR0	X0X0 0011₂
0049₁₆	External Space Wait Control Register 1(1)	EWCR1	X0X0 0011₂
004A₁₆	External Space Wait Control Register 2(1)	EWCR2	X0X0 0011₂
004B₁₆	External Space Wait Control Register 3(1)	EWCR3	X0X0 0011₂
004C₁₆			
004D₁₆			
004E₁₆			
004F₁₆			
0050₁₆			
0051₁₆			
0052₁₆			
0053₁₆			
0054₁₆			
0055₁₆	Flash Memory Control Register 1	FMR1	0000 0101₂
0056₁₆			
0057₁₆	Flash Memory Control Register 0	FMR0	0000 0001₂(Flash memory version) XXXX XXX0₂(Masked ROM version)
0058₁₆			
0059₁₆			
005A₁₆			
005B₁₆			
005C₁₆			
005D₁₆			
005E₁₆			
005F₁₆			

X: Indeterminate

Blank spaces are reserved. No access is allowed.

NOTES:

1. These registers cannot be used in M32C/85T.

Address	Register	Symbol	Value after RESET
012016	Base Timer Register 1	G1BT	XX16
012116			XX16
012216	Base Timer Control Register 10	G1BCR0	0016
012316	Base Timer Control Register 11	G1BCR1	X000 000X2
012416	Time Measurement Prescaler Register 16	G1TPR6	0016
012516	Time Measurement Prescaler Register 17	G1TPR7	0016
012616	Function Enable Register 1	G1FE	0016
012716	Function Select Register 1	G1FS	0016
012816	SI/O Receive Buffer Register 1	G1RB	XXXX XXXX2
012916			X000 XXXX2
012A16	Transmit Buffer/Receive Data Register 1	G1TB/G1DR	XX16
012B16			
012C16	Receive Input Register 1	G1RI	XX16
012D16	SI/O Communication Mode Register 1	G1MR	0016
012E16	Transmit Output Register 1	G1TO	XX16
012F16	SI/O Communication Control Register 1	G1CR	0000 X0112
013016	Data Compare Register 10	G1CMP0	XX16
013116	Data Compare Register 11	G1CMP1	XX16
013216	Data Compare Register 12	G1CMP2	XX16
013316	Data Compare Register 13	G1CMP3	XX16
013416	Data Mask Register 10	G1MSK0	XX16
013516	Data Mask Register 11	G1MSK1	XX16
013616			
013716			
013816	Receive CRC Code Register 1	G1RCRC	XX16
013916			XX16
013A16	Transmit CRC Code Register 1	G1TCRC	0016
013B16			0016
013C16	SI/O Extended Mode Register 1	G1EMR	0016
013D16	SI/O Extended Receive Control Register 1	G1ERC	0016
013E16	SI/O Special Communication Interrupt Detection Register 1	G1IRF	0016
013F16	SI/O Extended Transmit Control Register 1	G1ETC	0000 0XXX2
014016			
014116			
014216			
014316			
014416			
014516			
014616			
014716			
014816			
014916			
014A16			
014B16			
014C16			
014D16			
014E16			
014F16			

X: Indeterminate

Blank spaces are reserved. No access is allowed.

5. Electrical Characteristics

5.1 Electrical Characteristics (M32C/85)

Table 5.1 Absolute Maximum Ratings

Symbol	Parameter		Condition	Value	Unit
V_{CC1}, V_{CC2}	Supply Voltage		V_{CC1}=AV$_{CC}$	-0.3 to 6.0	V
V_{CC2}	Supply Voltage		-	-0.3 to V_{CC1}	V
AV$_{CC}$	Analog Supply Voltage		V_{CC1}=AV$_{CC}$	-0.3 to 6.0	V
V_I	Input Voltage	$\overline{RESET}$, CNV$_{SS}$, BYTE, P6$_0$-P6$_7$, P7$_2$-P7$_7$, P8$_0$-P8$_7$, P9$_0$-P9$_7$, P10$_0$-P10$_7$, P14$_0$-P14$_6$, P15$_0$-P15$_7$(1), V_{REF}, X$_{IN}$		-0.3 to V_{CC1}+0.3	V
		P0$_0$-P0$_7$, P1$_0$-P1$_7$, P2$_0$-P2$_7$, P3$_0$-P3$_7$, P4$_0$-P4$_7$, P5$_0$-P5$_7$, P11$_0$-P11$_4$, P12$_0$-P12$_7$, P13$_0$-P13$_7$(1)		-0.3 to V_{CC2}+0.3	
		P7$_0$, P7$_1$		-0.3 to 6.0	
V_O	Output Voltage	P6$_0$-P6$_7$, P7$_2$-P7$_7$, P8$_0$-P8$_4$, P8$_6$, P8$_7$, P9$_0$-P9$_7$, P10$_0$-P10$_7$, P14$_0$-P14$_6$, P15$_0$-P15$_7$(1), X$_{OUT}$		-0.3 to V_{CC1}+0.3	V
		P0$_0$-P0$_7$, P1$_0$-P1$_7$, P2$_0$-P2$_7$, P3$_0$-P3$_7$, P4$_0$-P4$_7$, P5$_0$-P5$_7$, P11$_0$-P11$_4$, P12$_0$-P12$_7$, P13$_0$-P13$_7$(1)		-0.3 to V_{CC2}+0.3	
		P7$_0$, P7$_1$		-0.3 to 6.0	
Pd	Power Dissipation		Topr=25° C	500	mW
Topr	Operating Ambient Temperature	during CPU operation		-20 to 85/ -40 to 85(2)	° C
		during flash memory program and erase operation		0 to 60	
Tstg	Storage Temperature			-65 to 150	° C

NOTES:
1. P11 to P15 are provided in the 144-pin package only.
2. Contact Renesas Technology Sales Co., Ltd, if temperature range of -40 to 85° C is required.

$V_{CC1}=V_{CC2}=5V$

Table 5.3 Electrical Characteristics

($V_{CC1}=V_{CC2}=4.2$ to 5.5V, $V_{SS}=0V$ at Topr= –20 to 85°C, f(BCLK)=32MHz unless otherwise specified)

Symbol	Parameter		Condition		Standard			Unit
					Min.	Typ.	Max.	
V_{OH}	Output High ("H") Voltage	$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$	I_{OH}=-5mA		V_{CC2}-2.0		V_{CC2}	V
		$P6_0$-$P6_7$, $P7_2$-$P7_7$, $P8_0$-$P8_4$, $P8_6$, $P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$, $P14_0$-$P14_6$, $P15_0$-$P15_7$(1)	I_{OH}=-5mA		V_{CC1}-2.0		V_{CC1}	
		$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$	I_{OH}=-200µA		V_{CC2}-0.3		V_{CC2}	V
		$P6_0$-$P6_7$, $P7_2$-$P7_7$, $P8_0$-$P8_4$, $P8_6$, $P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$,$P14_0$-$P14_6$, $P15_0$-$P15_7$(1)	I_{OH}=-200µA		V_{CC1}-0.3		V_{CC1}	
		X_{OUT}	I_{OH}=-1mA		3.0		V_{CC1}	V
		X_{COUT} High Power	No load applied			2.5		V
		X_{COUT} Low Power	No load applied			1.6		
V_{OL}	Output Low ("L") Voltage	$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P6_0$-$P6_7$, $P7_0$-$P7_7$, $P8_0$-$P8_4$, $P8_6$, $P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$, $P14_0$-$P14_6$, $P15_0$-$P15_7$(1)	I_{OL}=5mA				2.0	V
		$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P6_0$-$P6_7$, $P7_0$-$P7_7$, $P8_0$-$P8_4$, $P8_6$, $P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$, $P14_0$-$P14_6$, $P15_0$-$P15_7$(1)	I_{OL}=200µA				0.45	V
		X_{OUT}	I_{OL}=1mA				2.0	V
		X_{COUT} High Power	No load applied			0		V
		X_{COUT} Low Power	No load applied			0		
V_{T+}-V_{T-}	Hysteresis	$\overline{HOLD}$, $\overline{RDY}$, $TA0_{IN}$-$TA4_{IN}$, $TB0_{IN}$-$TB5_{IN}$, $\overline{INT0}$-$\overline{INT5}$, $\overline{ADTRG}$, $\overline{CTS0}$-$\overline{CTS4}$, CLK0-CLK4, $TA0_{OUT}$-$TA4_{OUT}$, $\overline{NMI}$, $\overline{KI0}$-$\overline{KI3}$, RxD0-RxD4, SCL0-SCL4, SDA0-SDA4			0.2		1.0	V
		$\overline{RESET}$			0.2		1.8	V
I_{IH}	Input High ("H") Current	$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P6_0$-$P6_7$, $P7_0$-$P7_7$, $P8_0$-$P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$, $P14_0$-$P14_6$, $P15_0$-$P15_7$(1), X_{IN}, $\overline{RESET}$, CNV_{SS}, BYTE	V_I=5V				5.0	µA
I_{IL}	Input Low ("L") Current	$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P6_0$-$P6_7$, $P7_0$-$P7_7$, $P8_0$-$P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$, $P14_0$-$P14_6$, $P15_0$-$P15_7$(1), X_{IN}, $\overline{RESET}$, CNV_{SS}, BYTE	V_I=0V				-5.0	µA
R_{PULLUP}	Pull-up Resistance	$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P6_0$-$P6_7$, $P7_2$-$P7_7$, $P8_0$-$P8_4$, $P8_6$, $P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$, $P14_0$-$P14_6$, $P15_0$-$P15_7$(1)	V_I=0V	Flash Memory	30	50	167	kΩ
				Masked ROM	20	40	167	
Rf_{XIN}	Feedback Resistance	X_{IN}				1.5		MΩ
Rf_{XCIN}	Feedback Resistance	X_{CIN}				10		MΩ
V_{RAM}	RAM Standby Voltage	In stop mode			2.0			V

NOTES:

1. P11 to P15 are provided in the 144-pin package only.

$V_{CC1}=V_{CC2}=5V$

Switching Characteristics

(V_{CC1} = V_{CC2} = 4.2 to 5.5V, V_{SS} = 0V at Topr = –20 to 85°C unless otherwise specified)

Table 5.22 Memory Expansion Mode and Microprocessor Mode (when accessing external memory space)

Symbol	Parameter	Measurement Condition	Standard		Unit
			Min.	Max.	
$td_{(BCLK-AD)}$	Address Output Delay Time	See Figure 5.2		18	ns
$th_{(BCLK-AD)}$	Address Output Hold Time (BCLK standard)		-3		ns
$th_{(RD-AD)}$	Address Output Hold Time (RD standard)(3)		0		ns
$th_{(WR-AD)}$	Address Output Hold Time (WR standard)(3)		(Note 1)		ns
$td_{(BCLK-CS)}$	Chip-Select Signal Output Delay Time			18	ns
$th_{(BCLK-CS)}$	Chip-Select Signal Output Hold Time (BCLK standard)		-3		ns
$th_{(RD-CS)}$	Chip-Select Signal Output Hold Time (RD standard)(3)		0		ns
$th_{(WR-CS)}$	Chip-Select Signal Output Hold Time (WR standard)(3)		(Note 1)		ns
$td_{(BCLK-RD)}$	RD Signal Output Delay Time			18	ns
$th_{(BCLK-RD)}$	RD Signal Output Hold Time		-5		ns
$td_{(BCLK-WR)}$	WR Signal Output Delay Time			18	ns
$th_{(BCLK-WR)}$	WR Signal Output Hold Time		-5		ns
$td_{(DB-WR)}$	Data Output Delay Time (WR standard)		(Note 2)		ns
$th_{(WR-DB)}$	Data Output Hold Time (WR standard)(3)		(Note 1)		ns
$tw_{(WR)}$	WR Output Width		(Note 2)		ns

NOTES:

1. Values can be obtained from the following equations, according to BCLK frequency.

$$th_{(WR-DB)} = \frac{10^9}{f_{(BCLK)} \times 2} - 10 \quad [ns]$$

$$th_{(WR-AD)} = \frac{10^9}{f_{(BCLK)} \times 2} - 10 \quad [ns]$$

$$th_{(WR-CS)} = \frac{10^9}{f_{(BCLK)} \times 2} - 10 \quad [ns]$$

2. Values can be obtained from the following equations, according to BCLK frequency and external bus cycles.

$$tw_{(WR)} = \frac{10^9 \times n}{f_{(BCLK)} \times 2} - 15 \quad [ns]$$ (if external bus cycle is aϕ + bϕ, n=(bx2)-1)

$$td_{(DB-WR)} = \frac{10^9 \times m}{f_{(BCLK)}} - 20 \quad [ns]$$ (if external bus cycle is aϕ + bϕ, m= b)

3. *tc* ns is added when recovery cycle is inserted.

$V_{CC1}=V_{CC2}=3.3V$

Timing Requirements

($V_{CC1}=V_{CC2}$= 3.0 to 3.6V, V_{SS}= 0V at Topr = –20 to 85°C unless otherwise specified)

Table 5.29 Timer A Input (Count Source Input in Event Counter Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TA)}$	TAi_{IN} Input Cycle Time	100		ns
$t_{w(TAH)}$	TAi_{IN} Input High ("H") Width	40		ns
$t_{w(TAL)}$	TAi_{IN} Input Low ("L") Width	40		ns

Table 5.30 Timer A Input (Gate Input in Timer Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TA)}$	TAi_{IN} Input Cycle Time	400		ns
$t_{w(TAH)}$	TAi_{IN} Input High ("H") Width	200		ns
$t_{w(TAL)}$	TAi_{IN} Input Low ("L") Width	200		ns

Table 5.31 Timer A Input (External Trigger Input in One-Shot Timer Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TA)}$	TAi_{IN} Input Cycle Time	200		ns
$t_{w(TAH)}$	TAi_{IN} Input High ("H") Width	100		ns
$t_{w(TAL)}$	TAi_{IN} Input Low ("L") Width	100		ns

Table 5.32 Timer A Input (External Trigger Input in Pulse Width Modulation Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{w(TAH)}$	TAi_{IN} Input High ("H") Width	100		ns
$t_{w(TAL)}$	TAi_{IN} Input Low ("L") Width	100		ns

Table 5.33 Timer A Input (Counter Increment/decrement Input in Event Counter Mode)

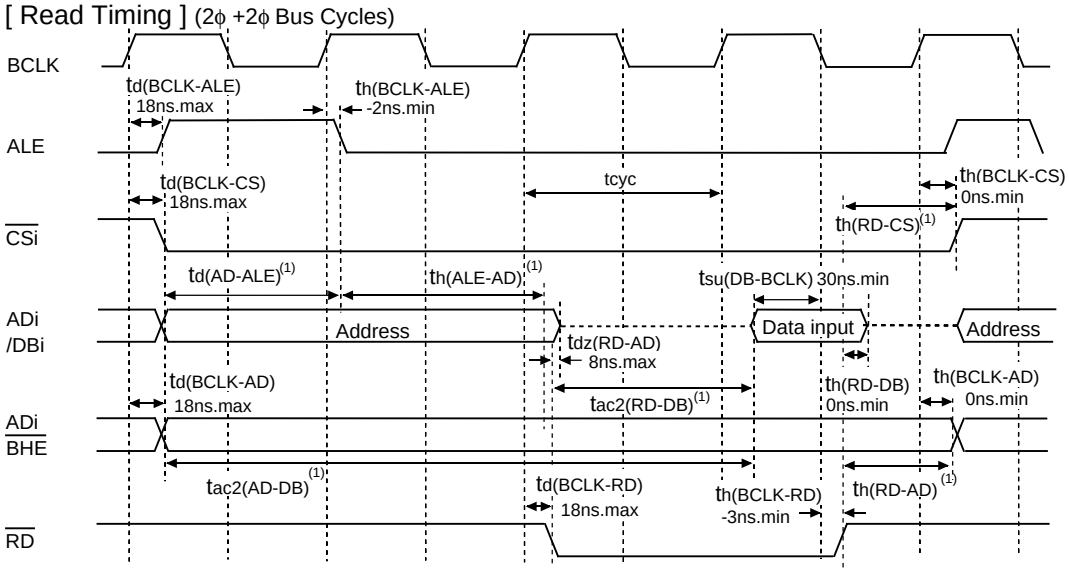
Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(UP)}$	TAi_{OUT} Input Cycle Time	2000		ns
$t_{w(UPH)}$	TAi_{OUT} Input High ("H") Width	1000		ns
$t_{w(UPL)}$	TAi_{OUT} Input Low ("L") Width	1000		ns
$t_{su(UP-TIN)}$	TAi_{OUT} Input Setup Time	400		ns
$t_{h(TIN-UP)}$	TAi_{OUT} Input Hold Time	400		ns

Memory Expansion Mode and Microprocessor Mode

Vcc1=Vcc2=3.3V

(when accessing external memory space and using the multiplexed bus)

[Read Timing] (2ϕ +2ϕ Bus Cycles)



NOTES:

1. Varies with operation frequency:

$t_{d(AD-ALE)}$=(tcyc/2 x n-20)ns.min (if external bus cycle is aϕ + bϕ, n=a)

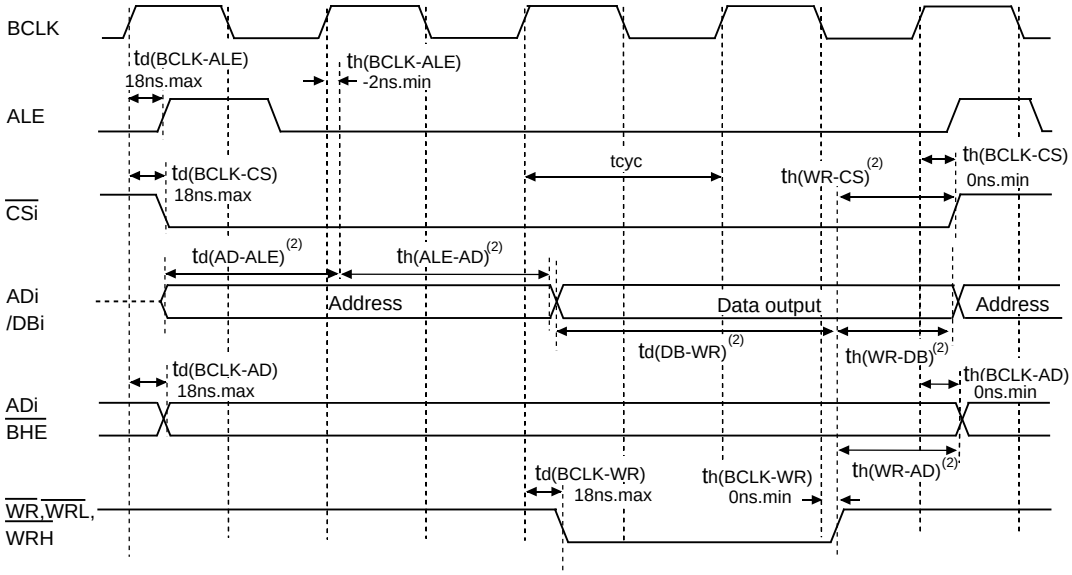
$t_{h(ALE-AD)}$=(tcyc/2 x n-10)ns.min (if external bus cycle is aϕ + bϕ, n=a)

$t_{h(RD-AD)}$=(tcyc/2-10)ns.min, $t_{h(RD-CS)}$=(tcyc/2-10)ns.min

$t_{ac2(RD-DB)}$=(tcyc/2 x m-35)ns.max (if external bus cycle is aϕ + bϕ, m=(b x 2)-1)

$t_{ac2(AD-DB)}$=(tcyc/2 x p-35)ns.max (if external bus cycle is aϕ + bϕ, p={(a+b-1) x 2}+1)

[Write Timing] (2ϕ +2ϕ Bus Cycles)



NOTES:

2. Varies with operation frequency:

$t_{d(AD-ALE)}$=(tcyc/2 x n - 20)ns.min

(if external bus cycle is aϕ + bϕ, n=a)

$t_{h(ALE-AD)}$=(tcyc/2 x n -10)ns.min

(if external bus cycle is aϕ + bϕ, n=a)

$t_{h(WR-AD)}$=(tcyc/2-10)ns.min,

$t_{h(WR-CS)}$=(tcyc/2-10)ns.min, $t_{h(WR-DB)}$=(tcyc/2-20)ns.min

$t_{d(DB-WR)}$=(tcyc/2 x m-25)ns.min

(if external bus cycle is aϕ + bϕ, m=(b x 2)-1)

Measurement Conditions:

- V_{CC1}=V_{CC2}=3.0 to 3.6V
- Input high and low voltage:
  V_{IH}=1.5V, V_{IL}=0.5V
- Output high and low voltage:
  V_{OH}=1.5V, V_{OL}=1.5V

$$tcyc = \frac{10^9}{f_{(BCLK)}}$$

Figure 5.8 V_{CC1}=V_{CC2}=3.3V Timing Diagram (2)

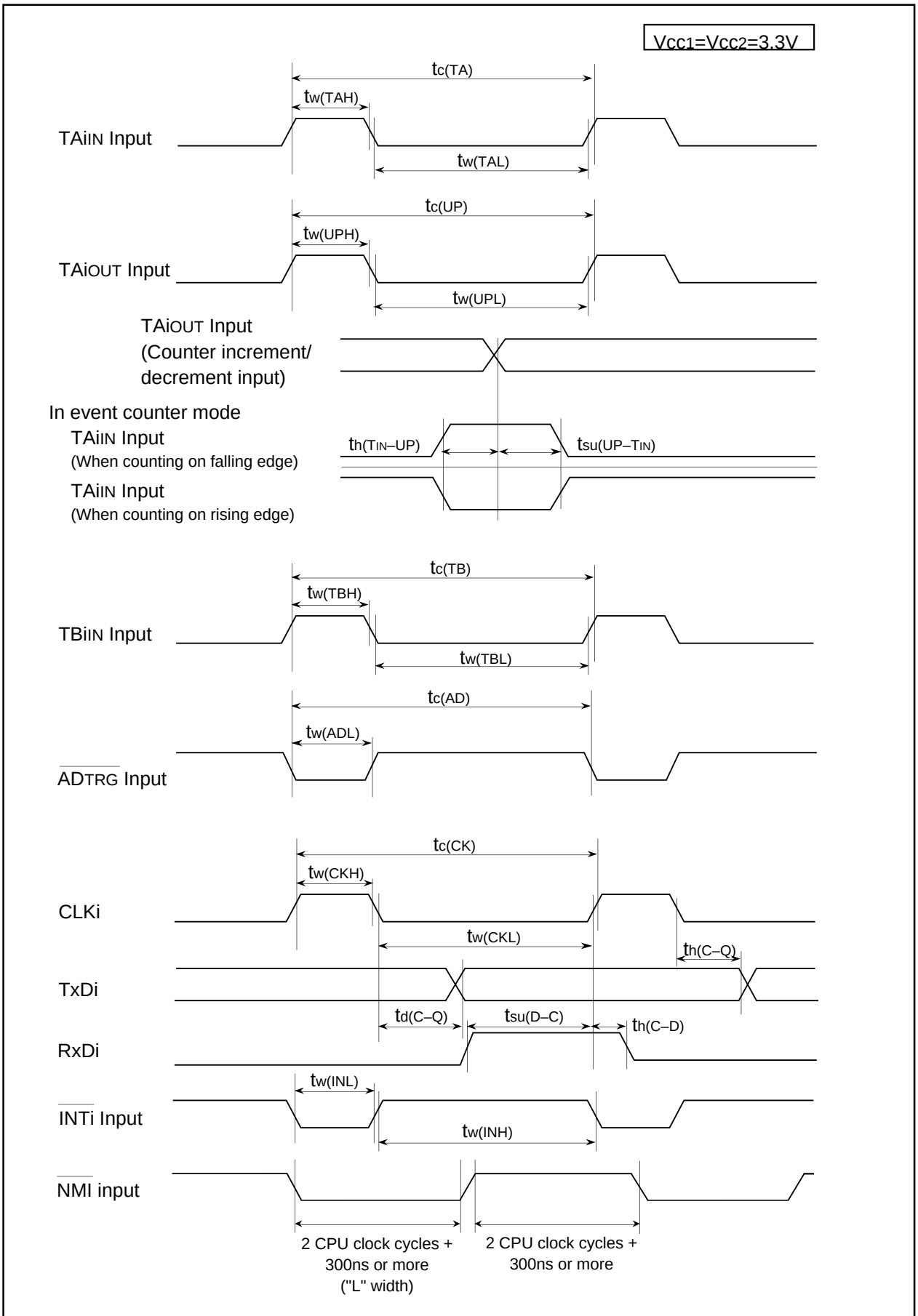


Figure 5.9 Vcc1=Vcc2=3.3V Timing Diagram (3)

5.2 Electrical Characteristics (M32C/85T)

Table 5.42 Absolute Maximum Ratings

Symbol	Parameter		Condition	Value	Unit
V_{CC1}, V_{CC2}	Supply Voltage		V_{CC1}=V_{CC2}=AVcc	-0.3 to 6.0	V
AVcc	Analog Supply Voltage		V_{CC1}=V_{CC2}=AVcc	-0.3 to 6.0	V
V_I	Input Voltage	$\overline{RESET}$, CNVss, BYTE, $P6_0$-$P6_7$, $P7_2$-$P7_7$, $P8_0$-$P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$, $P14_0$-$P14_6$, $P15_0$-$P15_7$(1), V_{REF}, X_{IN}		-0.3 to V_{CC1}+0.3	V
		$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$(1)		-0.3 to V_{CC2}+0.3	
		$P7_0$, $P7_1$		-0.3 to 6.0	
V_O	Output Voltage	$P6_0$-$P6_7$, $P7_2$-$P7_7$, $P8_0$-$P8_4$, $P8_6$, $P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$, $P14_0$-$P14_6$, $P15_0$-$P15_7$(1), X_{OUT}		-0.3 to V_{CC1}+0.3	V
		$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$(1)		-0.3 to V_{CC2}+0.3	
		$P7_0$, $P7_1$		-0.3 to 6.0	
Pd	Power Dissipation		Topr=25° C	500	mW
Topr	Operating Ambient Temperature	during CPU operation	T version	-40 to 85	° C
		during flash memory program and erase operation		0 to 60	
Tstg	Storage Temperature			-65 to 150	° C

NOTES:

1. P11 to P15 are provided in the 144-pin package only.

Table 5.43 Recommended Operating Conditions

(V_{CC1}=V_{CC2}=4.2 to 5.5V, V_{SS}=0V at Topr = -40 to 85°C (T version) unless otherwise specified)

Symbol	Parameter		Standard			Unit
			Min.	Typ.	Max.	
V_{CC1}, V_{CC2}	Supply Voltage (V_{CC1}≥ V_{CC2})		4.2	5.0	5.5	V
AVcc	Analog Supply Voltage			V_{CC1}		V
Vss	Supply Voltage			0		V
AVss	Analog Supply Voltage			0		V
V_{IH}	Input High ("H") Voltage	$P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$(4)	0.8V_{CC2}		V_{CC2}	V
		$P6_0$-$P6_7$, $P7_2$-$P7_7$, $P8_0$-$P8_7$(3), $P9_0$-$P9_7$, $P10_0$-$P10_7$, $P14_0$-$P14_6$, $P15_0$-$P15_7$(4), X_{IN}, $\overline{RESET}$, CNVss, BYTE	0.8V_{CC1}		V_{CC1}	
		$P7_0$, $P7_1$	0.8V_{CC1}		6.0	
		$P0_0$-$P0_7$, $P1_0$-$P1_7$	0.8V_{CC2}		V_{CC2}	
V_{IL}	Input Low ("L") Voltage	$P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$(4)	0		0.2V_{CC2}	V
		$P6_0$-$P6_7$, $P7_0$-$P7_7$, $P8_0$-$P8_7$(3), $P9_0$-$P9_7$, $P10_0$-$P10_7$, $P14_0$-$P14_6$, $P15_0$-$P15_7$(4), X_{IN}, $\overline{RESET}$, CNVss, BYTE	0		0.2V_{CC1}	
		$P0_0$-$P0_7$, $P1_0$-$P1_7$	0		0.2V_{CC2}	
$I_{OH(peak)}$	Peak Output High ("H") Current(2)	$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P6_0$-$P6_7$, $P7_2$-$P7_7$, $P8_0$-$P8_4$, $P8_6$, $P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$, $P14_0$-$P14_6$, $P15_0$-$P15_7$(4)			-10.0	mA
$I_{OH(avg)}$	Average Output High ("H") Current(1)	$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P6_0$-$P6_7$, $P7_2$-$P7_7$, $P8_0$-$P8_4$, $P8_6$, $P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$, $P14_0$-$P14_6$, $P15_0$-$P15_7$(4)			-5.0	mA
$I_{OL(peak)}$	Peak Output Low ("L") Current(2)	$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P6_0$-$P6_7$, $P7_0$-$P7_7$, $P8_0$-$P8_4$, $P8_6$, $P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$, $P14_0$-$P14_6$, $P15_0$-$P15_7$(4)			10.0	mA
$I_{OL(avg)}$	Average Output Low ("L") Current(1)	$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P6_0$-$P6_7$, $P7_0$-$P7_7$, $P8_0$-$P8_4$, $P8_6$, $P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$, $P14_0$-$P14_6$, $P15_0$-$P15_7$(4)			5.0	mA

NOTES:

1. Typical values when average output current is 100ms.
2. Total $I_{OL(peak)}$ for P0, P1, P2, $P8_6$, $P8_7$, P9, P10, P11, P14 and P15 must be 80mA or less.
   Total $I_{OL(peak)}$ for P3, P4, P5, P6, P7, $P8_0$ to $P8_4$, P12 and P13 must be 80mA or less.
   Total $I_{OH(peak)}$ for P0, P1, P2, and P11 must be -40mA or less.
   Total $I_{OH(peak)}$ for $P8_6$, $P8_7$, P9, P10, P14 and P15 must be -40mA or less.
   Total $I_{OH(peak)}$ for P3, P4, P5, P12 and P13 must be -40mA or less.
   Total $I_{OH(peak)}$ for P6, P7, and $P8_0$ to $P8_4$ must be -40mA or less.
3. V_{IH} and V_{IL} reference for $P8_7$ applies when $P8_7$ is used as a programmable input port.
   It does not apply when $P8_7$ is used as X_{CIN}.
4. P11 to P15 are provided in the 144-pin package only.

$V_{CC1}=V_{CC2}=5V$

Table 5.47 Flash Memory Version Electrical Characteristics

(V_{CC1}=4.5 to 5.5V, 3.0 to 3.6V at Topr= 0 to 60°C unless otherwise specified)

Symbol	Parameter		Standard			Unit
			Min.	Typ.	Max.	
-	Program and Erase Endurance(2)		100			cycles
-	Word Program Time (V_{CC1}=5.0V, Topr=25° C)			25	200	µs
-	Lock Bit Program Time			25	200	µs
-	Block Erase Time (V_{CC1}=5.0V, Topr=25° C)	4-Kbyte Block		0.3	4	s
		8-Kbyte Block		0.3	4	s
		32-Kbyte Block		0.5	4	s
		64-Kbyte Block		0.8	4	s
-	All-Unlocked-Block Erase Time(1)				4 x *n*	s
t_{PS}	Wait Time to Stabilize Flash Memory Circuit				15	µs
-	Data Hold Time (Topr=-40 to 85 ° C)		10			years

NOTES:
1. *n* denotes the number of block to be erased.
2. Number of program-erase cycles per block.
   If Program and Erase Endurance is *n* cycle (*n*=100), each block can be erased and programmed *n* cycles. For example, if a 4-Kbyte block A is erased after programming a word data 2,048 times, each to a different address, this counts as one program and erase endurance. Data can not be programmed to the same address more than once without erasing the block. (rewrite prohibited).

Table 5.48 Power Supply Timing

Symbol	Parameter	Measurement Condition	Standard			Unit
			Min.	Typ.	Max.	
td(P-R)	Wait Time to Stabilize Internal Supply Voltage when Power-on	V_{CC1}=3.0 to 5.5V			2	ms

$t_{d(P-R)}$
Wait Time to Stabilize Internal Supply Voltage when Power-on

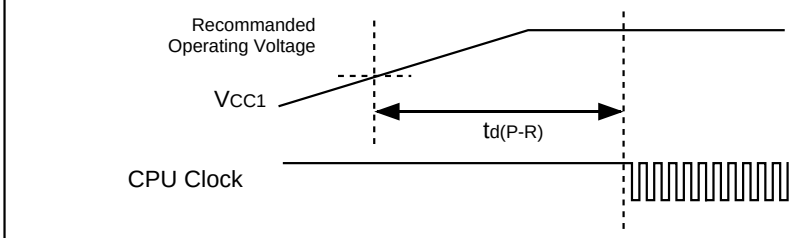


Figure 5.11 Power Supply Timing Diagram

Rev.	Date	Description	
		Page	Summary
			Electrical Characteristics
		50	• **Table 5.3 Electrical Characteristics** Maximum values for Power Supply Current modified
		52	• **Table 5.6 Flash Memory Version Electrical Characteristics** Note 1. 100-cycle Products (D3, D5, U3, U5) deleted; Note 4 modified
			• **Table 5.7 Flash Memory Version Program and Erase Voltage and Read Operation Voltage Characteristics (at Topr=0 to 60°C)** deleted
		63	• **Table 5.22 Electrical Characteristics** Maximum values for Power Supply Consumption modified and standard values when "Topr=85°C while clock is stopped" deleted
1.00	Jun.01, 2004	-	**M32C/85T (High-reliability version)** added
		All Pages	Words standardized: On-chip oscillator, A/D converter and D/A converter
			Overview
		1	• **1.1 Applications** Automobiles added
		2, 3	• **Table 1.1** and **Table 1.2 M32C/85 Group (M32C/85, M32C/85T) Performance** M32C/85T added; note 3 added
		4	• **Figure 1.1 M32C/85 Group (M32C/85, M32C/85T) Block Diagram** Note 3 added
		5	• **1.4 Product Information** Description modified
			• **Figure 1.2 ROM/RAM Capacity** figure modified
		5, 6	• **Table 1.3 M32C/85 Group** M32C/85T added
		6	• **Figure 1.3 Product Numbering System** M32C/85T added
		7	• **Figure 1.4 Pin Assignment for 144-Pin Package** Note 3 added
		12	• **Figure 1.6 Pin Assignment for 100-Pin Pacakage** Note 5 added
		8 to 10	• **Table 1.5 Pin Characteristics for 144-Pin Package** Note 1 added
		13, 14	• **Table 1.6 Pin Characteristics for 100-Pin Package** Note 1 added
		15 to 18	• **Table 1.7 Pin Description** Notes added
			Memory
		22	• **Figure 3.1 Memory Map** Tables of internal ROM/internal RAM modified; note 2 modified; notes 4 and 5 added
			SFR
		23	• Note 2 added
		24	• PWCR0 and PWCR1 registers deleted
			• "Values after RESET" of the masked ROM version added to the FMR0 register
			• Note 1 added
			Electrical Characteristics
		46	• **Table 5.2 Recommended Operating Conditions** $f_{(ripple)}$, $V_{p-p(ripple)}$, V_{CC}, SV_{CC} and note 1 deleted
		47	• **Table 5.3 Electrical Characteristics** R_{PULLUP} value for the masked ROM version added

REVISION HISTORY	M32C/85 Group (M32C/85, M32C/85T) Datasheet

Rev.	Date	Description	
		Page	Summary
		49	• **Table 5.3 Electrical Characteristics** Maximum ICC value modified
		50	• **Table 5.4 A/D Conversion Characteristics** tSMP value modified; note 1 added
		52	• **Table 5.7 Low Voltage Detect Circuit Electrical Characteristics** added
			• **Table 5.8 Power Supply Timing** added
			• **Figure 5.1 Power Supply Timing Diagram** added
		57	• **Table 5.23 Memory Expassion Mode and Microprocessor Mode** th(BCLK-ALE) value modified
		63	• **Table 5.24 Electrical Characteristics** Maximum ICC value modified
		61	• **Table 5.24 Electrical Characteristics** RPULLUP value for the masked ROM version added
		64	• **Table 5.25 A/D Conversion Characteristics** tCONV value modified
		65	• **Table 5.28 Memory Expassion Mode and Microprocessor Mode** tsu(DB-BCLK), tsu(RDY-BCLK) and tsu(HOLD-BCLK) value modified
		68	• **Table 5.40 Memory Expassion Mode and Microprocessor Mode** equetion of th(WR-DB) modified
		69	• **Table 5.41 Memory Expassion Mode and Microprocessor Mode** th(BCLK-ALE) value modified; equetion of th(WR-DB) modified
		74	• **5.2 Electrical Characteristics (M32C/85T)** added
1.10	Jun.28, 2004	-	**High-reliability version (U version)** deleted
			Overview
		5	• **Table 1.3 M32C/85 Group (1) (2)** development status modified
		6	• **Figure 1.2 Product Numbering System** figure modified
1.20	Mar.30, 2005		**Memory**
			• **Figure 3.1 Memory Map** A sentence added to Note 3
			SFR
		24	• Value after reset of the RLVL register revised
		27	• Value after reset of the G0RB register revised
		29	• Value after reset of the G1BCR1 register revised
			• Value after reset of the G1RB register revised
		37	• Value after reset of the IDB0 register revised
			• Value after reset of the IDB1 register revised
		43	• Value after reset of the PSC register revised
			Electrical Characteristics
		49	• **Table 5.3 Electrical Characteristics** ICC standard value revised
		51	• **Table 5.6 Flash Memory Electrical Characteristics** Topr value modified
		52	• **Table 5.7 Voltage Detection Circuit Electrical Characteristics** VCC1 value modified
		60	• **Figure 5.4 VCC1=VCC2=5V Timing Diagram (2)** Diagram modified
		63	• **Table 5.24 Electrical Characteristics** ICC standard value revised